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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	34
Program Memory Size	96KB (96K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	12K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 10x8/10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LFQFP (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104gfafb-50">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f104gfafb-50</a>

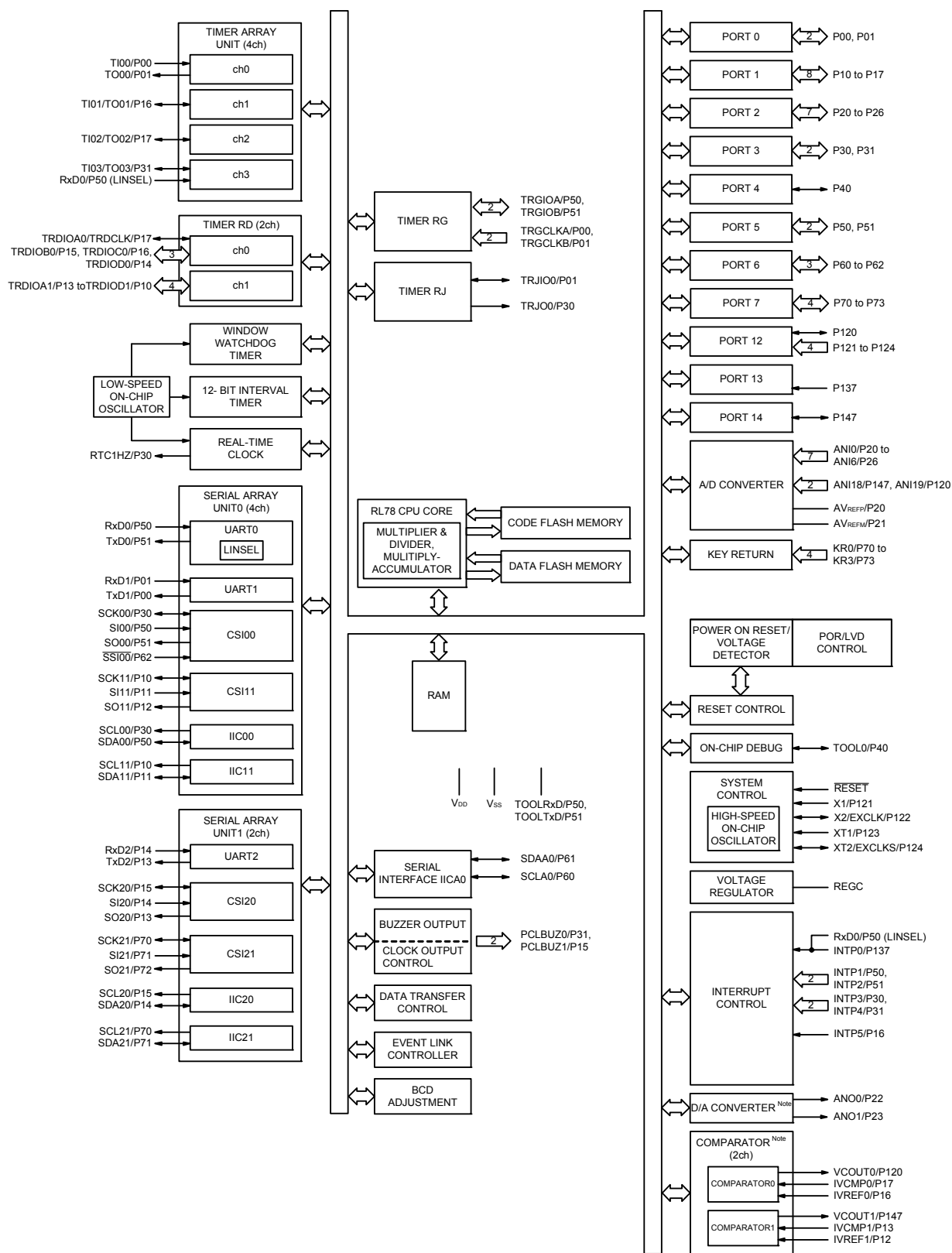
(1/5)

Pin count	Package	Fields of Application Note	Ordering Part Number
30 pins	30-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch)	A	R5F104AAASP#V0, R5F104ACASP#V0, R5F104ADASP#V0, R5F104AEASP#V0, R5F104AFASP#V0, R5F104AGASP#V0 R5F104AAASP#X0, R5F104ACASP#X0, R5F104ADASP#X0, R5F104AEASP#X0, R5F104AFASP#X0, R5F104AGASP#X0
		D	R5F104AADSP#V0, R5F104ACDSP#V0, R5F104ADDSP#V0, R5F104AEDSP#V0, R5F104AFDSP#V0, R5F104AGDSP#V0 R5F104AADSP#X0, R5F104ACDSP#X0, R5F104ADDSP#X0, R5F104AEDSP#X0, R5F104AFDSP#X0, R5F104AGDSP#X0
		G	R5F104AAGSP#V0, R5F104ACGSP#V0, R5F104ADGSP#V0, R5F104AEGSP#V0, R5F104AFGSP#V0, R5F104AGGSP#V0 R5F104AAGSP#X0, R5F104ACGSP#X0, R5F104ADGSP#X0, R5F104AEGSP#X0, R5F104AFGSP#X0, R5F104AGGSP#X0
32 pins	32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)	A	R5F104BAANA#U0, R5F104BCANA#U0, R5F104BDANA#U0, R5F104BEANA#U0, R5F104BFANA#U0, R5F104BGANA#U0 R5F104BAANA#W0, R5F104BCANA#W0, R5F104BDANA#W0, R5F104BEANA#W0, R5F104BFANA#W0, R5F104BGANA#W0
		D	R5F104BADNA#U0, R5F104BCDNA#U0, R5F104BDDNA#U0, R5F104BEDNA#U0, R5F104BFDNA#U0, R5F104BGDNA#U0 R5F104BADNA#W0, R5F104BCDNA#W0, R5F104BDDNA#W0, R5F104BEDNA#W0, R5F104BFDNA#W0, R5F104BGDNA#W0
		G	R5F104BAGNA#U0, R5F104BCGNA#U0, R5F104BDGNA#U0, R5F104BEGNA#U0, R5F104BFGNA#U0, R5F104BGGNA#U0 R5F104BAGNA#W0, R5F104BCGNA#W0, R5F104BDGNA#W0, R5F104BEGNA#W0, R5F104BFGNA#W0, R5F104BGGNA#W0
	32-pin plastic LQFP (7 × 7, 0.8 mm pitch)	A	R5F104BAAFP#V0, R5F104BCAFP#V0, R5F104BDAFP#V0, R5F104BEAFP#V0, R5F104BFAFP#V0, R5F104BGAFP#V0 R5F104BAAFP#X0, R5F104BCAFP#X0, R5F104BDAFP#X0, R5F104BEAFP#X0, R5F104BFAFP#X0, R5F104BGAFP#X0
		D	R5F104BADFP#V0, R5F104BCDFP#V0, R5F104BDDFP#V0, R5F104BEDFP#V0, R5F104BDFP#V0, R5F104BGDFP#V0 R5F104BADFP#X0, R5F104BCDFP#X0, R5F104BDDFP#X0, R5F104BEDFP#X0, R5F104BDFP#X0, R5F104BGDFP#X0
		G	R5F104BAGFP#V0, R5F104BCGFP#V0, R5F104BDGFP#V0, R5F104BEGFP#V0, R5F104BFGFP#V0, R5F104BGGFP#V0 R5F104BAGFP#X0, R5F104BCGFP#X0, R5F104BDGFP#X0, R5F104BEGFP#X0, R5F104BFGFP#X0, R5F104BGGFP#X0
36 pins	36-pin plastic WFLGA (4 × 4 mm, 0.5 mm pitch)	A	R5F104CAALA#U0, R5F104CCALA#U0, R5F104CDALA#U0, R5F104CEALA#U0, R5F104CFALA#U0, R5F104CGALA#U0 R5F104CAALA#W0, R5F104CCALA#W0, R5F104CDALA#W0, R5F104CEALA#W0, R5F104CFALA#W0, R5F104CGALA#W0
		G	R5F104CAGLA#U0, R5F104CCGLA#U0, R5F104CDGLA#U0, R5F104CEGLA#U0, R5F104CFGLA#U0, R5F104CGGLA#U0 R5F104CAGLA#W0, R5F104CCGLA#W0, R5F104CDGLA#W0, R5F104CEGLA#W0, R5F104CFGLA#W0, R5F104CGGLA#W0

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

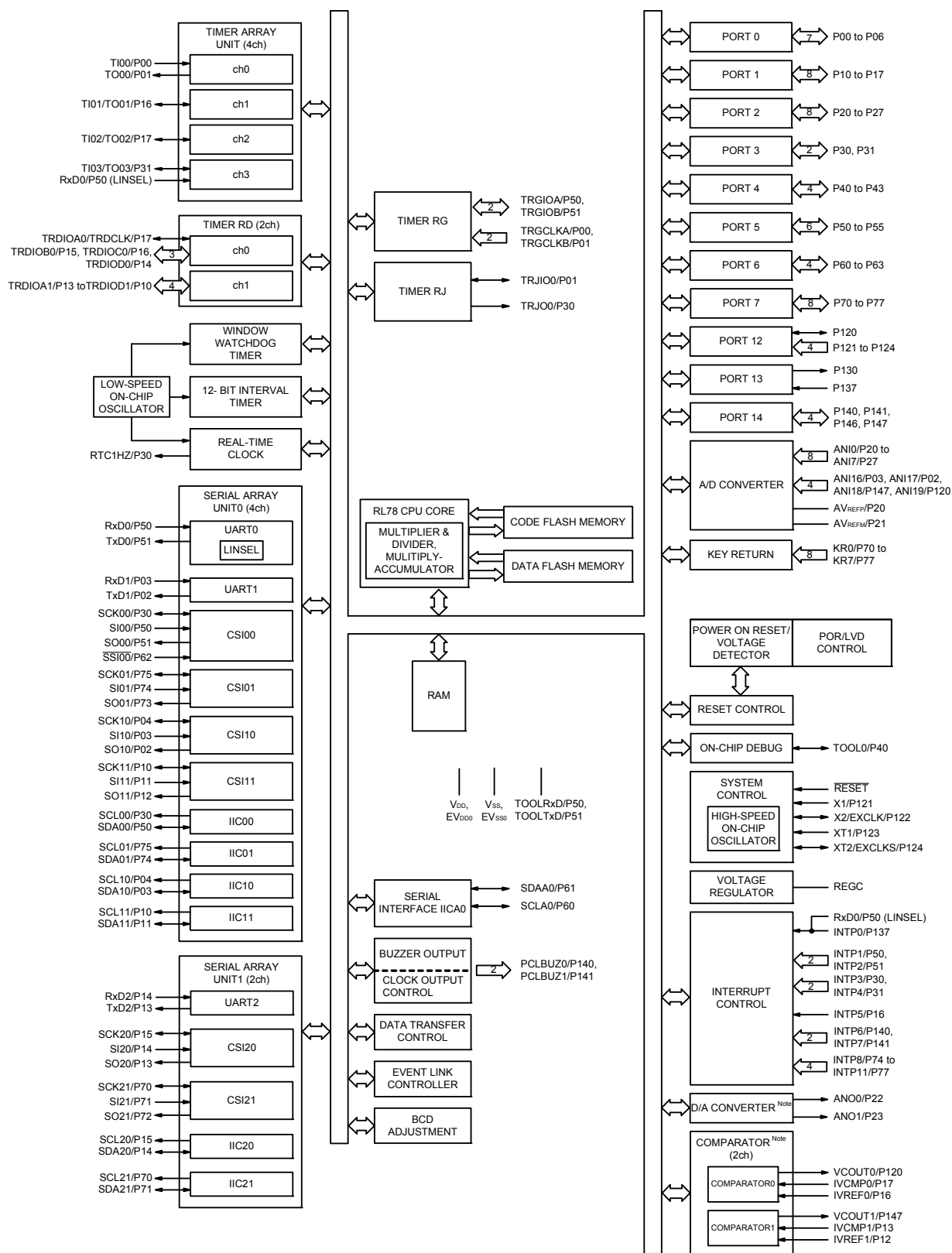
**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

### 1.5.4 40-pin products



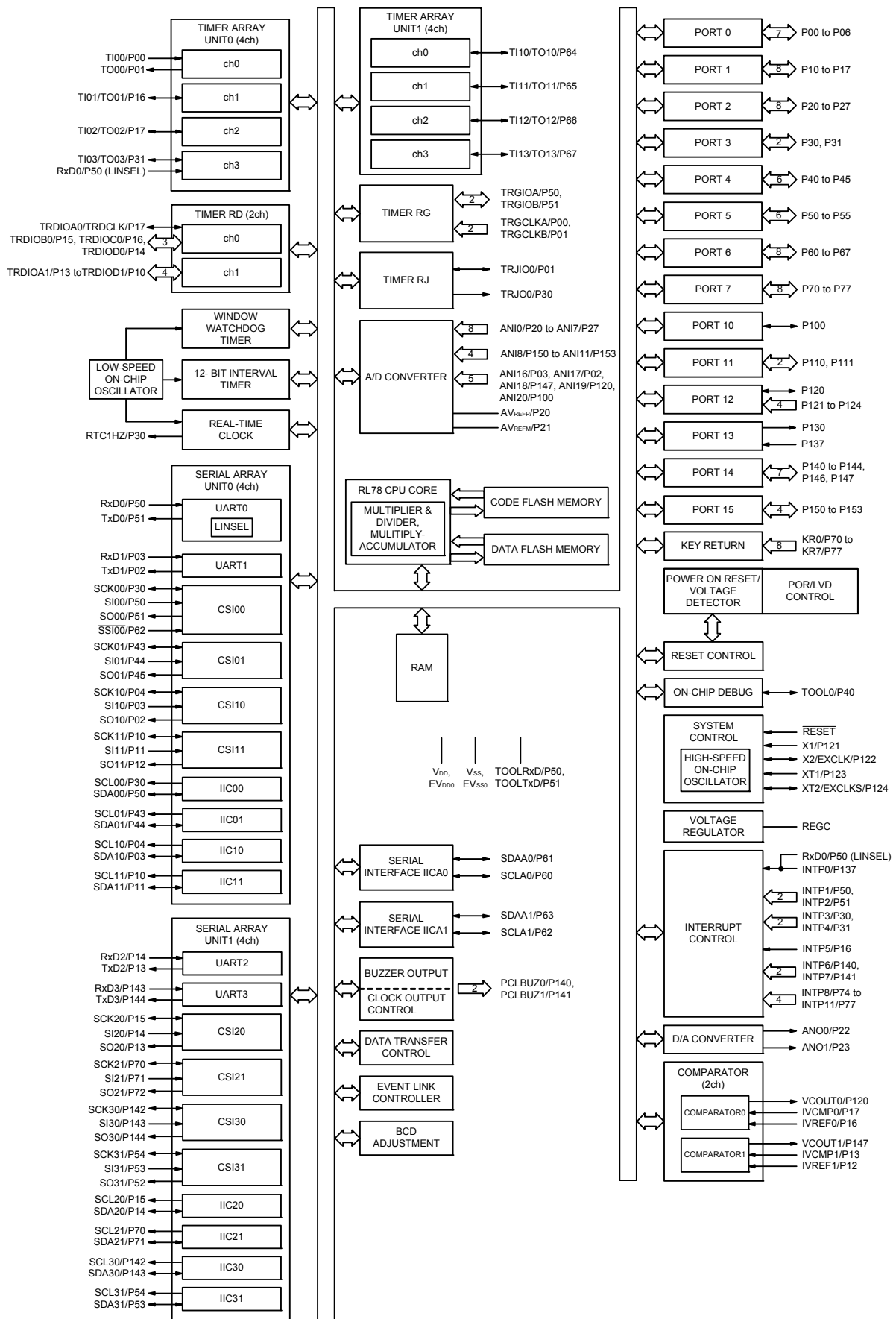
**Note** Mounted on the 96 KB or more code flash memory products.

## 1.5.8 64-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

### 1.5.9 80-pin products



- Note 1.** Total current flowing into VDD, EVDD0, and EVDD1, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD0, and EVDD1, or VSS, EVSS0, and EVSS1. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |                                     |
|-----------------------------|-------------------------------------|
| HS (high-speed main) mode:  | 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ VDD ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ VDD ≤ 5.5 V@1 MHz to 4 MHz  |
- Remark 1.** fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** fHOCO: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** fIH: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is TA = 25°C

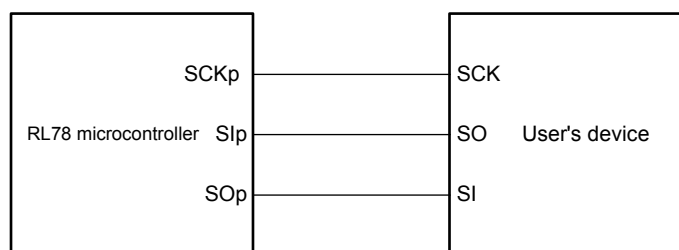
- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz  |
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

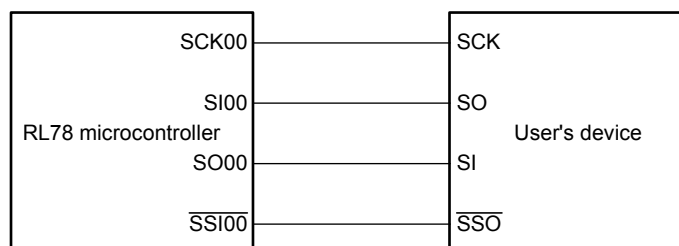
Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SSI00 setup time	tSSIK	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	120		120		120	ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	200		200		200	ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	400		400		400	ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		400		400	ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120	ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200	ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400	ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400	ns
SSI00 hold time	tKSSI	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120	ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200	ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400	ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400	ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	120		120		120	ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	200		200		200	ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	400		400		400	ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		400		400	ns

**Caution** Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM number (g = 3, 5)

**CSI mode connection diagram (during communication at same potential)**

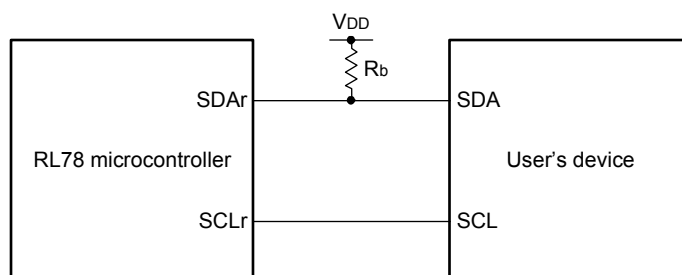
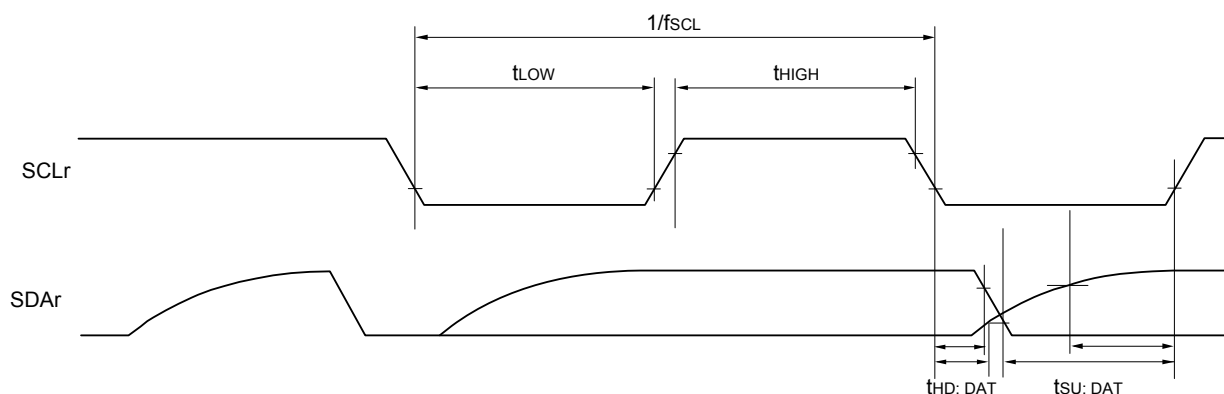
**CSI mode connection diagram (during communication at same potential)**  
**(Slave Transmission of slave select input function (CSI00))**



**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)



**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**

**Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance

**Remark 2.** r: IIC number (r = 00, 01, 10, 11, 20, 21, 30, 31), g: PIM number (g = 0, 1, 3 to 5, 14),  
h: POM number (h = 0, 1, 3 to 5, 7, 14)

**Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), mn = 00 to 03, 10 to 13)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate		reception	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	fMCK/6 Note 1		fMCK/6 Note 1		fMCK/6 Note 1	bps
				5.3		1.3		0.6	Mbps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4						
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	fMCK/6 Note 1		fMCK/6 Note 1		fMCK/6 Note 1	bps
				5.3		1.3		0.6	Mbps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4						
			1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V	fMCK/6 Notes 1, 2, 3		fMCK/6 Notes 1, 2		fMCK/6 Notes 1, 2	bps
				5.3		1.3		0.6	Mbps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4						

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** Use it with EVDD0 ≥ Vb.**Note 3.** The following conditions are required for low voltage interface when EVDD0 < VDD.

2.4 V ≤ EVDD0 &lt; 2.7 V: MAX. 2.6 Mbps

1.8 V ≤ EVDD0 &lt; 2.4 V: MAX. 1.3 Mbps

**Note 4.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

LS (low-speed main) mode: 8 MHz (1.8 V ≤ VDD ≤ 5.5 V)

LV (low-voltage main) mode: 4 MHz (1.6 V ≤ VDD ≤ 5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

**Remark 1.** Vb [V]: Communication line voltage**Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

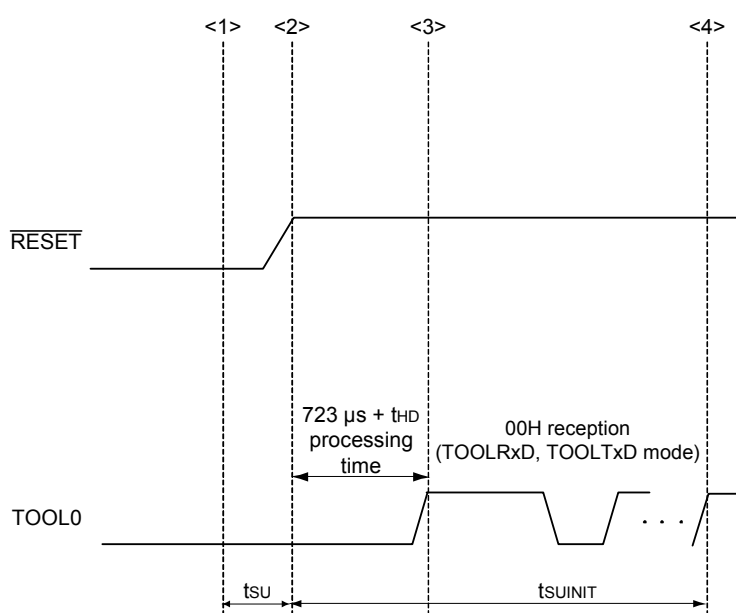
n: Channel number (mn = 00 to 03, 10 to 13)

**Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

## 2.10 Timing of Entry to Flash Memory Programming Modes

(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	tsuINIT	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	tsu	POR and LVD reset must end before the external reset ends.	10			μs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	tHD	POR and LVD reset must end before the external reset ends.	1			ms



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** tsuINIT: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends

tHD: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

Operation of products rated “G: Industrial applications ( $T_A = -40$  to  $+105^\circ\text{C}$ )” at ambient operating temperatures above  $85^\circ\text{C}$  differs from that of products rated “A: Consumer applications” and “D: Industrial applications” in the ways listed below.

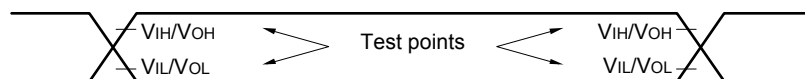
Parameter	A: Consumer applications, D: Industrial applications	G: Industrial applications
Operating ambient temperature	$T_A = -40$ to $+85^\circ\text{C}$	$T_A = -40$ to $+105^\circ\text{C}$
Operating mode Operating voltage range	HS (high-speed main) mode: $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$ $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$ LS (low-speed main) mode: $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }8\text{ MHz}$ LV (low-voltage main) mode: $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }4\text{ MHz}$	HS (high-speed main) mode only: $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$ $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
High-speed on-chip oscillator clock accuracy	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ : $\pm 1.0\%$ @ $T_A = -20$ to $+85^\circ\text{C}$ $\pm 1.5\%$ @ $T_A = -40$ to $-20^\circ\text{C}$ $1.6\text{ V} \leq V_{DD} < 1.8\text{ V}$ : $\pm 5.0\%$ @ $T_A = -20$ to $+85^\circ\text{C}$ $\pm 5.5\%$ @ $T_A = -40$ to $-20^\circ\text{C}$	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ : $\pm 2.0\%$ @ $T_A = +85$ to $+105^\circ\text{C}$ $\pm 1.0\%$ @ $T_A = -20$ to $+85^\circ\text{C}$ $\pm 1.5\%$ @ $T_A = -40$ to $-20^\circ\text{C}$
Serial array unit	UART CSI: $f_{CLK}/2$ (16 Mbps supported), $f_{CLK}/4$ Simplified I <sup>2</sup> C communication	UART CSI: $f_{CLK}/4$ Simplified I <sup>2</sup> C communication
IICA	Standard mode Fast mode Fast mode plus	Standard mode Fast mode
Voltage detector	<ul style="list-style-type: none"> <li>Rising: 1.67 V to 4.06 V (14 stages)</li> <li>Falling: 1.63 V to 3.98 V (14 stages)</li> </ul>	<ul style="list-style-type: none"> <li>Rising: 2.61 V to 4.06 V (8 stages)</li> <li>Falling: 2.55 V to 3.98 V (8 stages)</li> </ul>

**Remark** The electrical characteristics of products rated “G: Industrial applications ( $T_A = -40$  to  $+105^\circ\text{C}$ )” at ambient operating temperatures above  $85^\circ\text{C}$  differ from those of products rated “A: Consumer applications” and “D: Industrial applications”. For details, refer to 3.1 to 3.10.

- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

### 3.5 Peripheral Functions Characteristics

#### AC Timing Test Points



#### 3.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq 5.5\text{ V}$ ,  $\text{Vss} = \text{EVss0} = \text{EVss1} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate Note 1		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$		$f_{\text{MCK}}/12$ Note 2	bps
		Theoretical value of the maximum transfer rate $f_{\text{MCK}} = f_{\text{CLK}}$ Note 3		2.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when  $\text{FRQSEL4} = 1$ .

**Note 2.** The following conditions are required for low voltage interface when  $\text{EVDD0} < \text{VDD}$ .

$2.4\text{ V} \leq \text{EVDD0} < 2.7\text{ V}$ : MAX. 1.3 Mbps

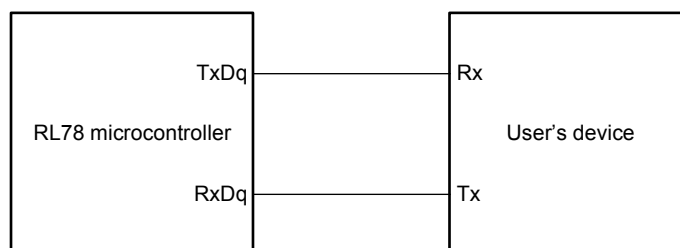
**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{\text{CLK}}$ ) are:

HS (high-speed main) mode: 32 MHz ( $2.7\text{ V} \leq \text{VDD} \leq 5.5\text{ V}$ )

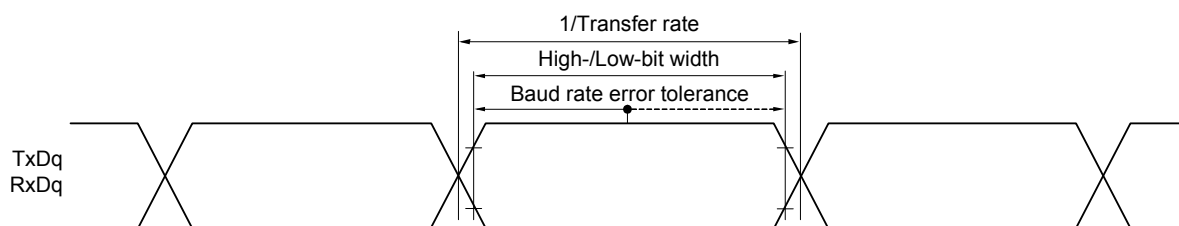
16 MHz ( $2.4\text{ V} \leq \text{VDD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remark 1.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 2.**  $f_{\text{MCK}}$ : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10 to 13))

**(4) During communication at same potential (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{\text{SCL}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 Note 1	kHz
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$		100 Note 1	kHz
Hold time when SCLr = "L"	$t_{\text{LOW}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Hold time when SCLr = "H"	$t_{\text{HIGH}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1200		ns
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	4600		ns
Data setup time (reception)	$t_{\text{SU: DAT}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 220$ Note 2		ns
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	$1/f_{\text{MCK}} + 580$ Note 2		ns
Data hold time (transmission)	$t_{\text{HD: DAT}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	0	1420	ns

**Note 1.** The value must also be equal to or less than  $f_{\text{MCK}}/4$ .**Note 2.** Set the  $f_{\text{MCK}}$  value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the normal input buffer and the N-ch open drain output ( $\text{V}_{\text{DD}}$  tolerance (for the 30- to 52-pin products)/ $\text{EV}_{\text{DD}}$  tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		HS (high-speed main) mode		Unit
				MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	600		ns
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	1000		ns
			2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	2300		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	t <sub>KCY1</sub> /2 - 150		ns	
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	t <sub>KCY1</sub> /2 - 340		ns	
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	t <sub>KCY1</sub> /2 - 916		ns	
SCKp low-level width	t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	t <sub>KCY1</sub> /2 - 24		ns	
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	t <sub>KCY1</sub> /2 - 36		ns	
		2.4 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	t <sub>KCY1</sub> /2 - 100		ns	

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)



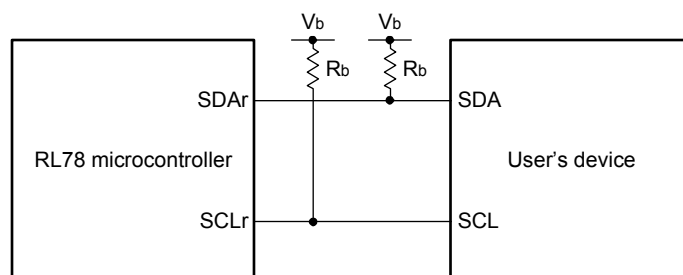
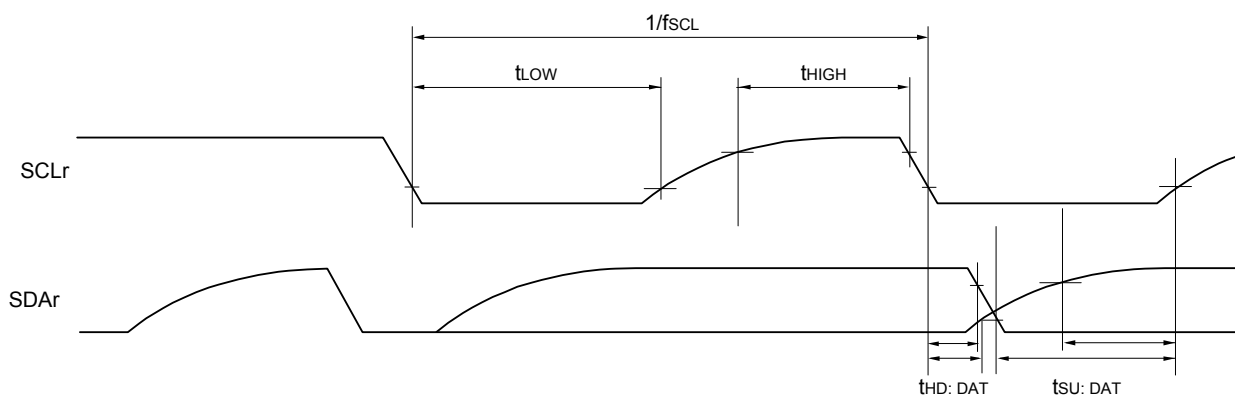
**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Data setup time (reception)	$t_{\text{SU:DAT}}$	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 340$ Note 2		ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 340$ Note 2		ns
		$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	$1/f_{\text{MCK}} + 760$ Note 2		ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{\text{MCK}} + 760$ Note 2		ns
		$2.4\text{ V} \leq \text{EVDD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$1/f_{\text{MCK}} + 570$ Note 2		ns
Data hold time (transmission)	$t_{\text{HD:DAT}}$	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	770	ns
		$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	0	1420	ns
		$2.7\text{ V} \leq \text{EVDD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	1420	ns
		$2.4\text{ V} \leq \text{EVDD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	0	1215	ns

**Note 1.** The value must also be equal to or less than  $f_{\text{MCK}}/4$ .**Note 2.** Set the  $f_{\text{MCK}}$  value to keep the hold time of  $\text{SCLr} = \text{"L"}$  and  $\text{SCLr} = \text{"H"}$ .

**Caution** Select the TTL input buffer and the N-ch open drain output ( $\text{VDD}$  tolerance (for the 30- to 52-pin products)/ $\text{EVDD}$  tolerance (for the 64- to 100-pin products)) mode for the  $\text{SDAr}$  pin and the N-ch open drain output ( $\text{VDD}$  tolerance (for the 30- to 52-pin products)/ $\text{EVDD}$  tolerance (for the 64- to 100-pin products)) mode for the  $\text{SCLr}$  pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{\text{IH}}$  and  $V_{\text{IL}}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

**Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage

**Remark 2.**  $r$ : IIC number ( $r = 00, 01, 10, 11, 20, 30, 31$ ),  $g$ : PIM, POM number ( $g = 0, 1, 3$  to  $5, 14$ )

**Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  $m$ : Unit number ( $m = 0, 1$ ),  
 $n$ : Channel number ( $n = 0, 2$ ),  $mn = 00, 01, 02, 10, 12, 13$ )

### 3.6.4 Comparator

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage range	Ivref		0		$\text{EVDD0} - 1.4$	V
	Ivcmp		-0.3		$\text{EVDD0} + 0.3$	V
Output delay	td	$\text{VDD} = 3.0\text{ V}$ Input slew rate $> 50\text{ mV}/\mu\text{s}$ Comparator high-speed mode, standard mode			1.2	$\mu\text{s}$
		Comparator high-speed mode, window mode			2.0	$\mu\text{s}$
		Comparator low-speed mode, standard mode		3.0	5.0	$\mu\text{s}$
High-electric-potential reference voltage	VTW+	Comparator high-speed mode, window mode		$0.76\text{ VDD}$		V
Low-electric-potential reference voltage	VTW-	Comparator high-speed mode, window mode		$0.24\text{ VDD}$		V
Operation stabilization wait time	tcMP		100			$\mu\text{s}$
Internal reference voltage Note	VBGR	$2.4\text{ V} \leq \text{VDD} \leq 5.5\text{ V}$ , HS (high-speed main) mode	1.38	1.45	1.50	V

**Note** Not usable in sub-clock operation or STOP mode.

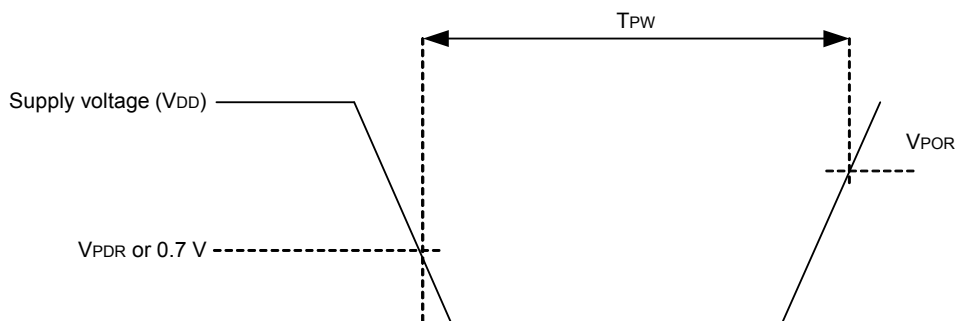
### 3.6.5 POR circuit characteristics

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $\text{VSS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	VPOR	Voltage threshold on $\text{VDD}$ rising	1.45	1.51	1.57	V
	VPDR	Voltage threshold on $\text{VDD}$ falling Note 1	1.44	1.50	1.56	V
Minimum pulse width Note 2	TPW		300			$\mu\text{s}$

**Note 1.** However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 3.4 AC Characteristics.

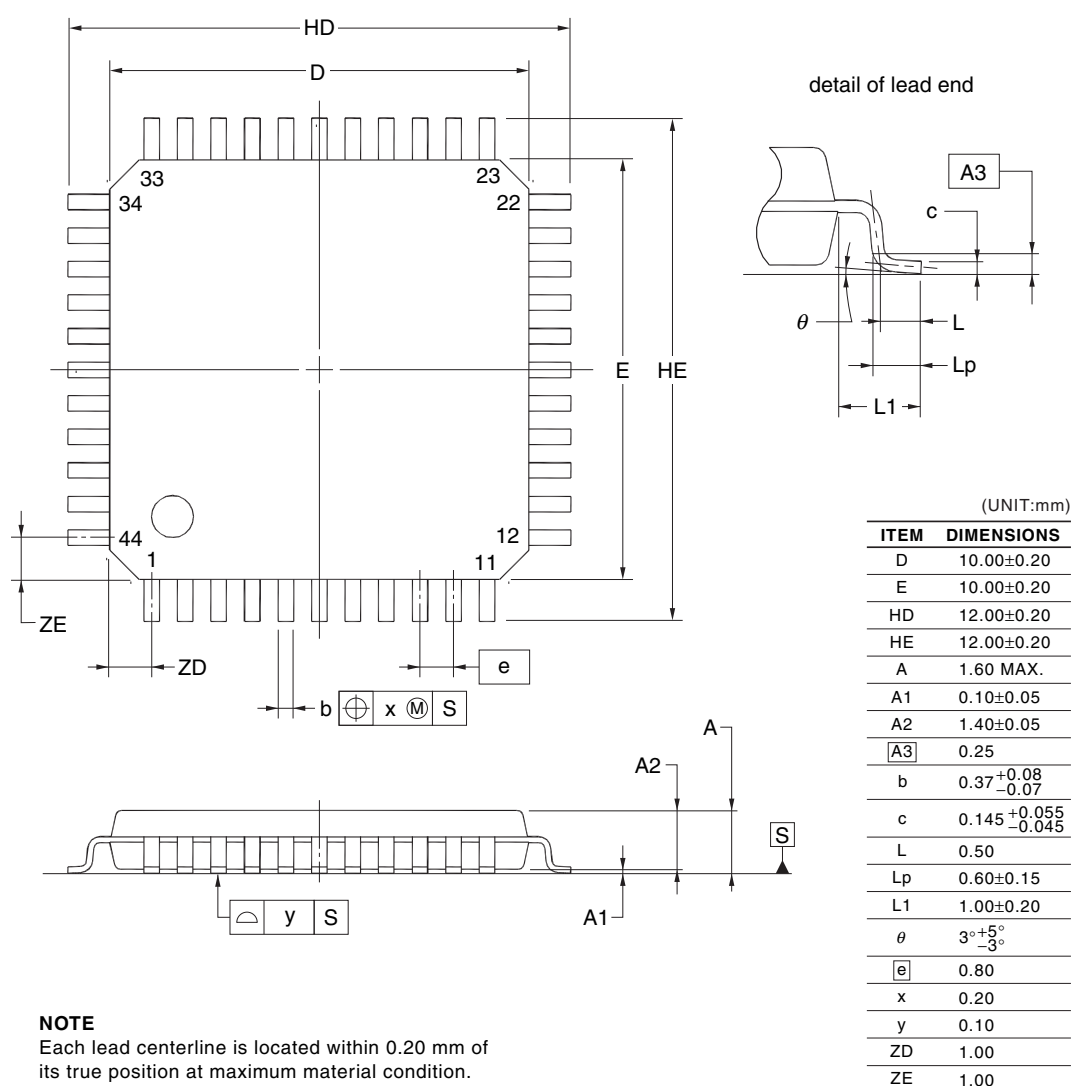
**Note 2.** Minimum time required for a POR reset when  $\text{VDD}$  exceeds below  $\text{VPDR}$ . This is also the minimum time required for a POR reset from when  $\text{VDD}$  exceeds below  $0.7\text{ V}$  to when  $\text{VDD}$  exceeds  $\text{VPOR}$  while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 4.5 44-pin products

R5F104FAAFP, R5F104FCAFP, R5F104FDAFP, R5F104FEAFP, R5F104FFAFP, R5F104FGAFP,  
 R5F104FHAFP, R5F104FJAFP  
 R5F104FADFP, R5F104FCDFP, R5F104FDDFP, R5F104FEDFP, R5F104FFDFP, R5F104FGDFP,  
 R5F104FHDFP, R5F104FJDFP  
 R5F104FAGFP, R5F104FCGFP, R5F104FDGFP, R5F104FEGFP, R5F104FFGFP, R5F104FGGFP,  
 R5F104FHGFP, R5F104FJGFP

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP44-10x10-0.80	PLQP0044GC-A	P44GB-80-UES-2	0.36



R5F104MKAFB, R5F104MLAFB  
R5F104MKGFB, R5F104MLGFB

